

**STPR120A**

## HIGH EFFICIENCY FAST RECOVERY DIODE

### MAIN PRODUCT CHARACTERISTICS

I <sub>F(AV)</sub>	1 A
V <sub>RRM</sub>	200 V
t <sub>rr</sub> (max)	35 ns

### FEATURES AND BENEFITS

- VERY LOW SWITCHING LOSSES
- LOW FORWARD VOLTAGE DROP
- SURFACE MOUNT DEVICE
- FAST RECTIFIER EPITAXIAL DIODE



SMA

### DESCRIPTION

Single chip rectifier suited to Switched Mode Power Supplies and high frequency DC/DC converters.

Packaged in SMA, this surface mount device is intended for use in low voltage, high frequency inverters, free wheeling and polarity protection applications.

### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter	Value	Unit
V <sub>RRM</sub>	Repetitive peak reverse voltage	200	V
I <sub>F(RMS)</sub>	RMS forward current	8	A
I <sub>F(AV)</sub>	Average forward current	1	A
I <sub>FSM</sub>	Surge non repetitive forward current	30	A
T <sub>stg</sub>	Storage temperature range	- 65 to + 150	°C
T <sub>j</sub>	Maximum junction temperature	150	°C

### THERMAL RESISTANCES

Symbol	Parameter	Value	Unit
R <sub>th (j-l)</sub>	Junction to lead	30	°C/W

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### STATIC ELECTRICAL CHARACTERISTICS

Symbol	Tests Conditions	Tests Conditions		Min.	Typ.	Max.	Unit
$I_R$ *	Reverse leakage current	$T_j = 25^\circ C$	$V_R = V_{RRM}$			3	$\mu A$
		$T_j = 125^\circ C$			180	400	
$V_F$ **	Forward voltage drop	$T_j = 25^\circ C$	$I_F = 1 A$			0.94	$V$
		$T_j = 150^\circ C$	$I_F = 1 A$		0.69	0.74	

Pulse test : \*  $t_p = 5ms$ ,  $\delta < 2\%$

\*\*  $t_p = 380 \mu s$ ,  $\delta < 2\%$

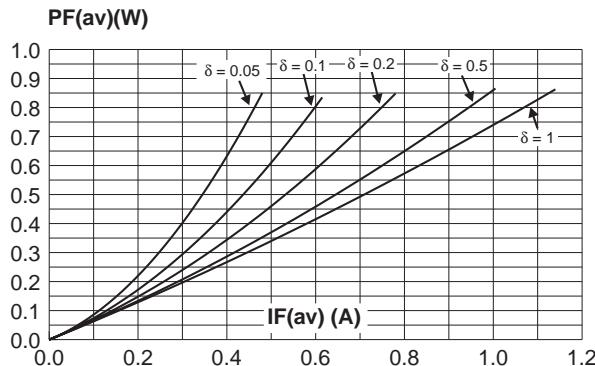
### RECOVERY CHARACTERISTICS

Symbol	Tests Conditions			Min.	Typ.	Max.	Unit
$t_{rr}$	$T_j = 25^\circ C$	$I_F = 0.50 A$	$I_{rr} = 0.25 A$			25	$ns$
		$I_F = 1 A$	$dI_F/dt = 50 A/\mu s$		25	35	
$t_{FR}$	$T_j = 25^\circ C$	$I_F = 1 A$	$dI_F/dt = 100 A/\mu s$			25	
$V_{FP}$	$T_j = 25^\circ C$	$I_F = 1 A$	$dI_F/dt = 100 A/\mu s$			5	$V$

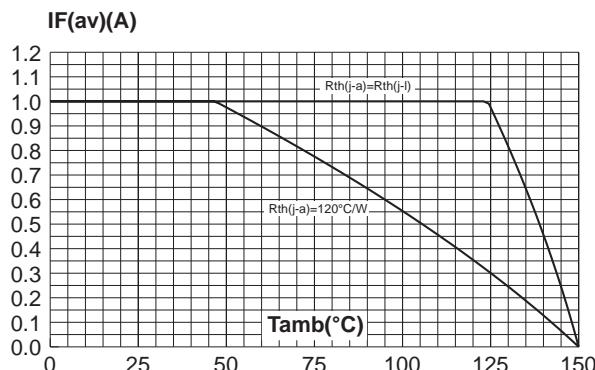
To evaluate the maximum conduction losses use the following equation :

$$P = 0.62 \times I_{F(AV)} + 0.12 \times I_F^2(RMS)$$

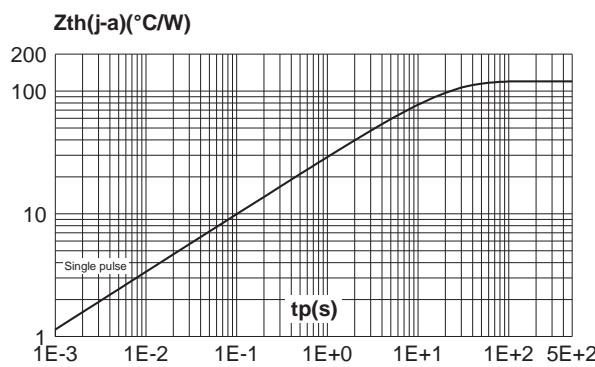
**Fig. 1:** Average forward power dissipation versus average forward current.



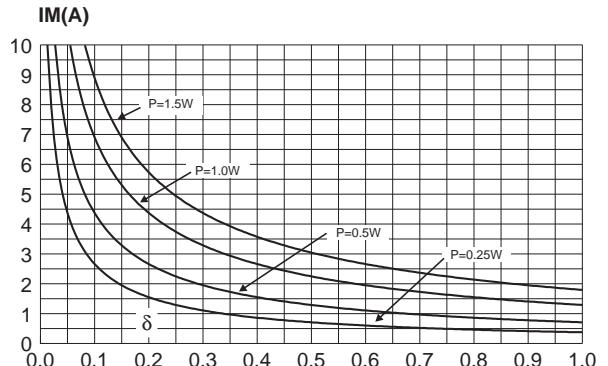
**Fig. 3:** Average forward current versus ambient temperature ( $\delta=0.5$ ).



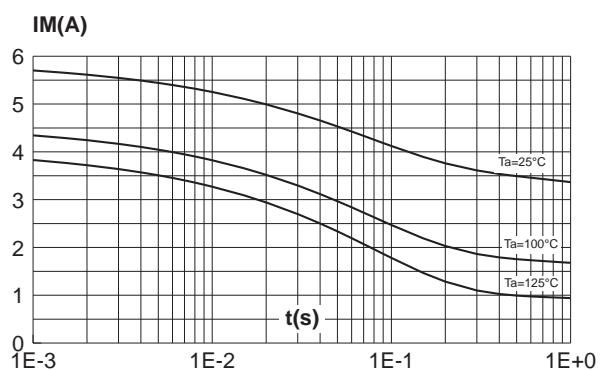
**Fig. 5:** Variation of thermal impedance junction to ambient versus pulse duration (Recommended pad layout, epoxy FR4,  $e(\text{Cu})=35\mu\text{m}$ ).



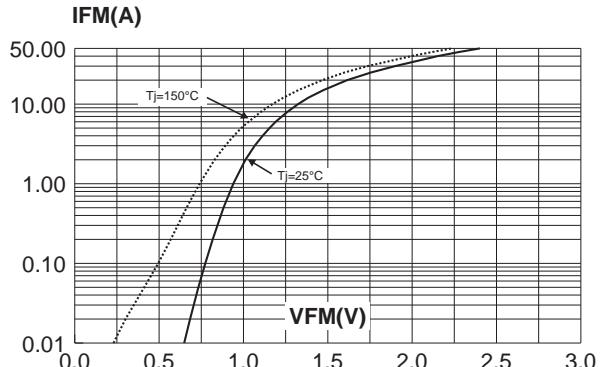
**Fig. 2:** Peak current versus form factor.



**Fig. 4:** Non repetitive surge peak forward current versus overload duration.



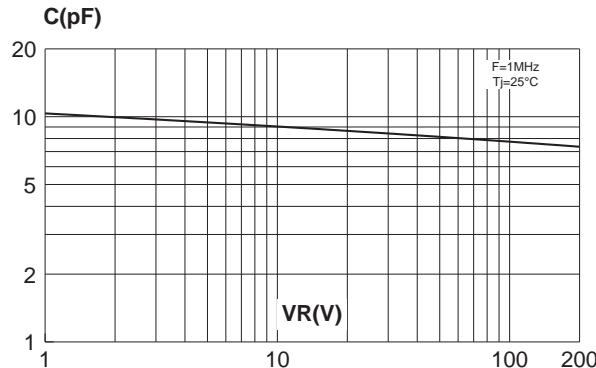
**Fig. 6:** Forward voltage drop versus forward current (maximum values).



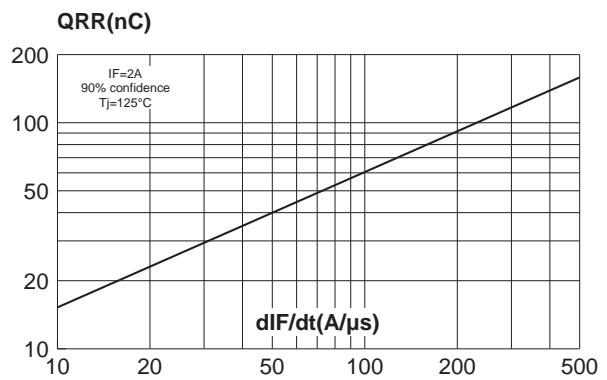
## STPR120A

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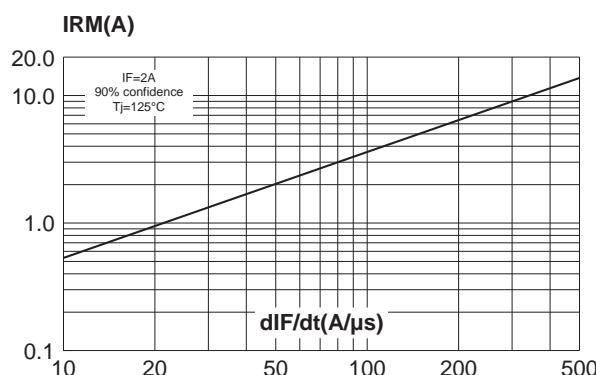
**Fig. 7:** Junction capacitance versus reverse voltage applied (typical values).



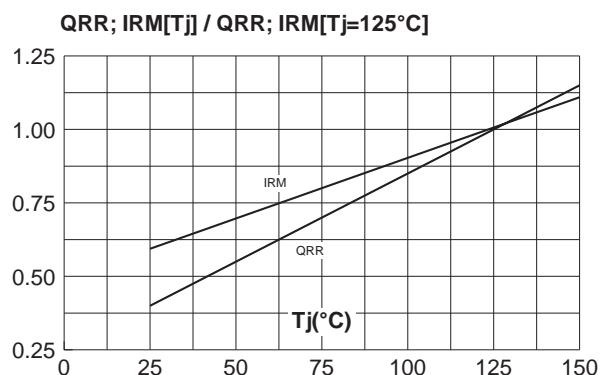
**Fig. 8:** Recovery charges versus  $dI_F/dt$



**Fig. 9:** Peak reverse recovery current versus  $dI_F/dt$ .



**Fig. 10:** Dynamic parameters versus junction temperature.

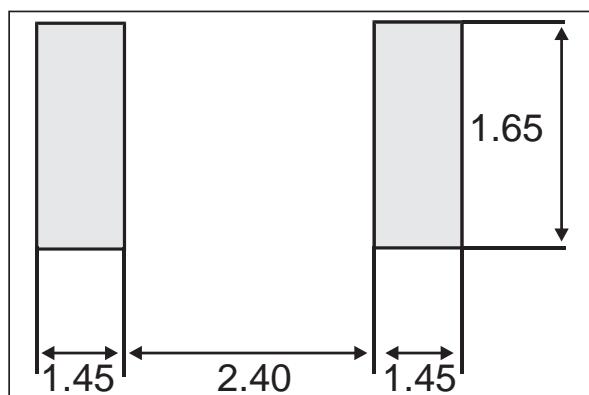


## PACKAGE MECHANICAL DATA

SMA

REF.	DIMENSIONS			
	Millimeters		Inches	
	Min.	Max.	Min.	Max.
A1	1.90	2.70	0.075	0.106
A2	0.05	0.20	0.002	0.008
b	1.25	1.65	0.049	0.065
c	0.15	0.41	0.006	0.016
E	4.80	5.60	0.189	0.220
E1	3.95	4.60	0.156	0.181
D	2.25	2.95	0.089	0.116
L	0.75	1.60	0.030	0.063

### FOOT PRINT (in millimeters)



- **Marking :** R12
- Cathode band is inked
- Epoxy meets UL94-V0
- Weight: 0.06g

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